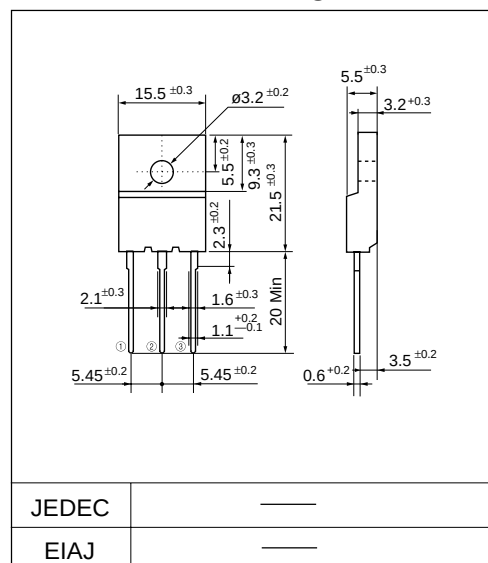


ESAD85M-009R (25A) (90V / 25A)

SCHOTTKY BARRIER DIODE

■ Outline drawings, mm



■ Features

- Insulated package by fully molding
- Low V_F
- Super high speed switching
- High reliability by planer design

■ Applications

- High speed power switching

■ Maximum ratings and characteristics

- Absolute maximum ratings

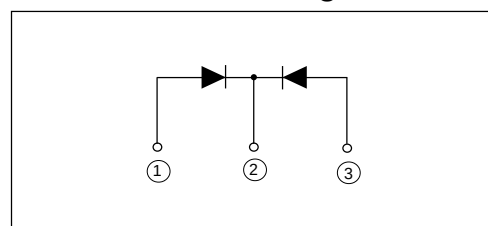
Item	Symbol	Conditions	Ratings	Unit
Repetitive peak reverse voltage	V_{RRM}		90	V
Non-repetitive peak reverse voltage	V_{RSM}	$t_w=500ns$, duty=1/40	100	V
Isolating voltage	V_{iso}	Terminals-to-case, AC. 1min.	1500	V
Average output current	I_o	Square wave, duty=1/2 $T_c=100^{\circ}C$	25*	A
Suege current	I_{FSM}	Sine wave 10ms	150	A
Operating junction temperature	T_j		-40 to +150	$^{\circ}C$
Storage temperature	T_{stg}		-40 to +150	$^{\circ}C$

* Average forward current of centertap full wave connection

- Electrical characteristics ($T_a=25^{\circ}C$ Unless otherwise specified)

Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V_{FM}	$I_{FM}=10A$	0.9	V
Reverse current	I_{RRM}	$V_R=V_{RRM}$	20	mA
Thermal resistance	$R_{th(j-c)}$	Junction to case	1.7	$^{\circ}C/W$

■ Connection diagram

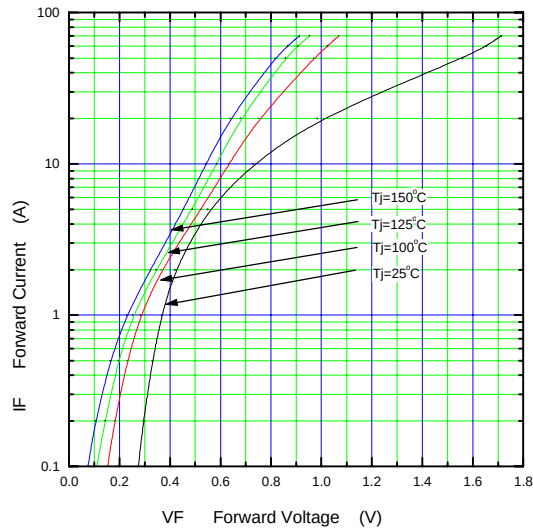


(90V / 25A)

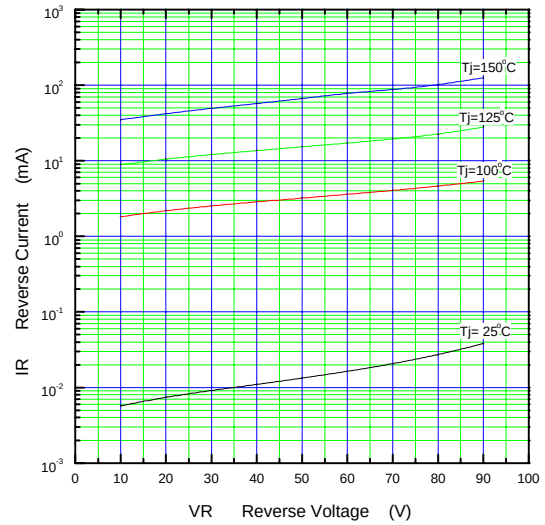
ESAD85M-009R (25A)

Characteristics

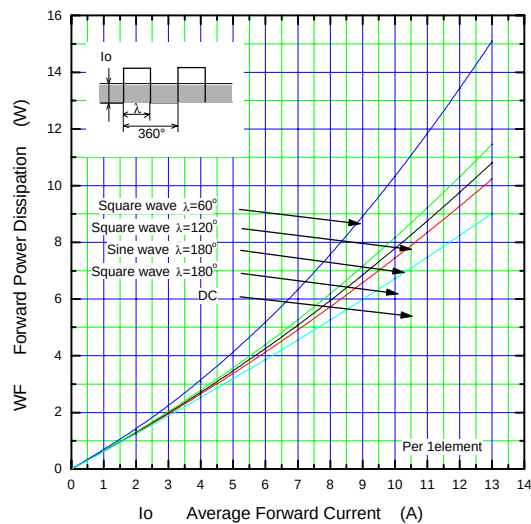
Forward Characteristic (typ.)



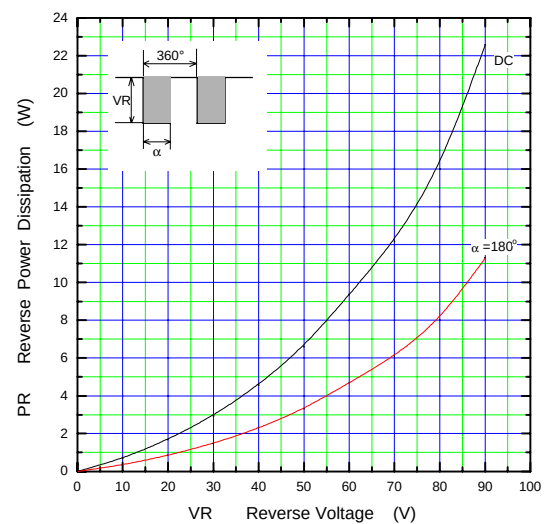
Reverse Characteristic (typ.)



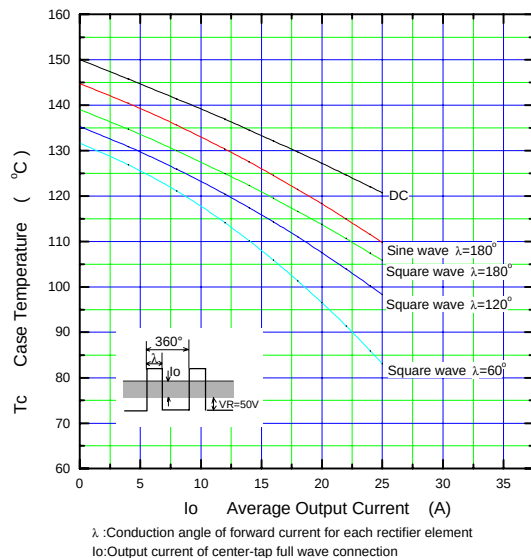
Forward Power Dissipation



Reverse Power Dissipation



Current Derating (I_o - T_c)



Junction Capacitance Characteristic (typ.)

